Unit: mm

#### TOSHIBA Schottky Barrier Diode

### **CMS17**

## Switching Mode Power Supply Applications Portable Equipment Battery Applications

- Forward voltage:  $V_{FM} = 0.48 \text{ V (max)}$
- Average forward current: If (AV) = 2.0 A
- Repetitive peak reverse voltage:  $V_{RRM} = 30 \text{ V}$
- Suitable for compact assembly due to a small surface-mount package: "M-FLAT<sup>TM</sup>" (Toshiba package name)"

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Repetitive peak reverse voltage	$V_{RRM}$	30	V
Average forward current	I <sub>F (AV)</sub>	2.0 (Note 1)	Α
Nonrepetitive peak surge current	I <sub>FSM</sub>	30 (50 Hz)	Α
Junction temperature	Tj	<b>−40~150</b>	°C
Storage temperature range	T <sub>stg</sub>	<b>−40~150</b>	°C

Note 1:  $Ta = 77^{\circ}C$ 

Device mounted on a ceramic board

Board size: 50 mm  $\times$  50 mm Soldering size: 2 mm  $\times$  2 mm Board thickness: 0.64 t

Rectangular waveform ( $\alpha = 180^{\circ}$ ),  $V_R = 15 \text{ V}$ 

Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook

("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test

www.DataSheet4U.coreport and estimated failure rate, etc).

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Weight: 0.023 g (typ.)

#### **Electrical Characteristics (Ta = 25°C)**

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit	
Peak forward voltage	V <sub>FM (1)</sub>	I <sub>FM</sub> = 1.0 A (pulse test)	_	0.42	_	- V	
l eak lorward voltage	V <sub>FM (2)</sub>	I <sub>FM</sub> = 2.0 A (pulse test)	_	0.45	0.48		
Dook ropotitivo rovorgo gurrant	I <sub>RRM (1)</sub>	V <sub>RRM</sub> = 5 V (pulse test)	_	0.8	_	ш	
Peak repetitive reverse current	I <sub>RRM (2)</sub>	V <sub>RRM</sub> = 30 V (pulse test)	_	10	100 µA		
Junction capacitance	Cj	V <sub>R</sub> = 10 V, f = 1.0 MHz	_	90	_	pF	
Thermal resistance (junction to ambient)	R <sub>th (j-a)</sub>	Device mounted on a ceramic board (board size: 50 mm × 50 mm) (soldering land: 2 mm × 2 mm) (board thickness: 0.64 t)	_	_	60		
		Device mounted on a glass-epoxy board (board size: 50 mm × 50 mm) (soldering land: 6 mm × 6 mm) (board thickness: 1.6 t)		_	135	°C/W	
		Device mounted on a glass-epoxy board (board size: 50 mm × 50 mm) (soldering land: 2.1 mm × 1.4 mm) (board thickness: 1.6 t)	_	_	210		
Thermal resistance (junction to lead)	R <sub>th (j-ℓ)</sub>	_	_	_	16	°C/W	

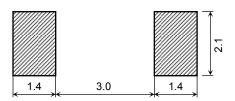


#### Marking

Abbreviation Code	Part No.		
SG	CMS17		

#### **Standard Soldering Pad**

Unit: mm



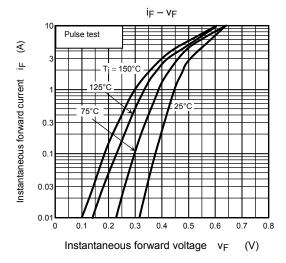
#### **Handling Precaution**

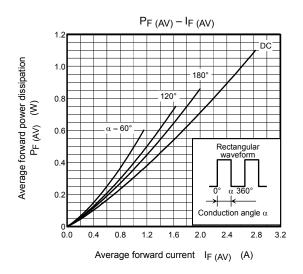
- 1) Schottky barrier diodes have reverse current characteristics compared to other diodes. SBDs can cause thermal runaway when used under high temperature or high voltage conditions. Be sure to take forward and reverse loss into consideration during design.
- 2) The absolute maximum ratings denote the absolute maximum ratings, which are rated values that must not be exceeded during operation, even for an instant. The following are the general derating methods that we recommend for designing a circuit incorporating this device.
  - VRRM: Use this rating with reference to (1) above. VRRM has a temperature coefficient of 0.1%/°C. Take this temperature coefficient into account when designing a device for operation at low temperature.
  - IF (AV): We recommend that the worst case current be no greater than 80% of the absolute maximum rating of

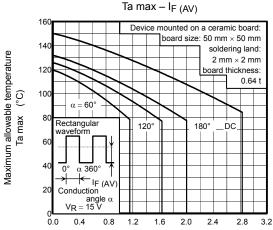
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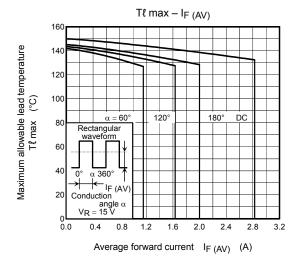
 $I_{F(AV)}$  and that  $T_{j}$  be below 120°C. When using this device, take the margin into consideration by using an allowable Tamax- $I_{F(AV)}$  curve.

- IFSM: This rating specifies the nonrepetitive peak current. This is applied only for abnormal operation, which seldom occurs during the lifespan of the device.
- T<sub>j</sub>: Derate this rating when using the device to ensure high reliability. We recommend that the device be used at a T<sub>j</sub> of below 120°C.
- 3) Thermal resistance between junction and ambient fluctuates depending on the mounting condition of the device. When using the device, design the circuit board and soldering land size to match the appropriate thermal resistance value.
- 4) Refer to the Rectifiers databook for further information.

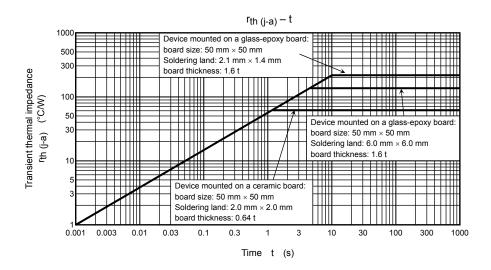




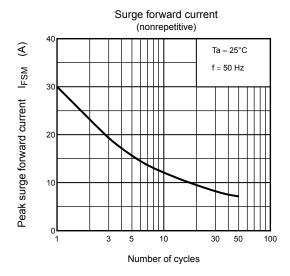


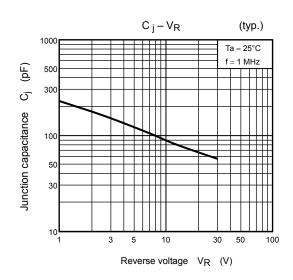


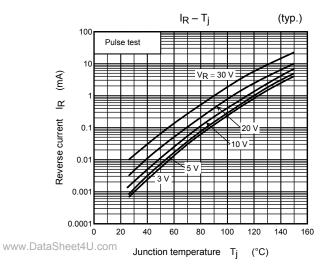
www.DataSheet4U.com  $_{\mbox{Average forward current}}$   $_{\mbox{I}_{\mbox{F (AV)}}}$  (A)

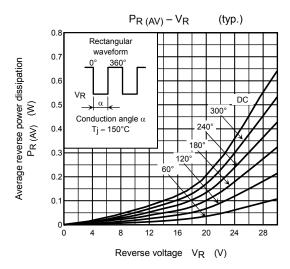


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